# TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS145E

#### August 1997 - Revised March 2004

#### Features

- Unlimited Input Rise and Fall Times
- Exceptionally High Noise Immunity
- Typical Propagation Delay: 10ns at  $V_{CC} = 5V$ ,  $C_L = 15pF$ ,  $T_A = 25^{\circ}C$
- Fanout (Over Temperature Range)
  - Standard Outputs ..... 10 LSTTL Loads
  - Bus Driver Outputs ..... 15 LSTTL Loads
- Wide Operating Temperature Range ... -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
  - 2V to 6V Operation
  - High Noise Immunity: N<sub>IL</sub> = 37%, N<sub>IH</sub> = 51% of V<sub>CC</sub> at V<sub>CC</sub> = 5V
- HCT Types
  - 4.5V to 5.5V Operation
  - Direct LSTTL Input Logic Compatibility, V<sub>IL</sub>= 0.8V (Max), V<sub>IH</sub> = 2V (Min)
  - CMOS Input Compatibility, II  $\leq$  1 $\mu\text{A}$  at VOL, VOH

# CD54HC132, CD74HC132, CD54HCT132, CD74HCT132

### High-Speed CMOS Logic Quad 2-Input NAND Schmitt Trigger

#### Description

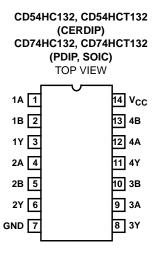
The 'HC132 and 'HCT132 each contain four 2-input NAND Schmitt Triggers in one package. This logic device utilizes silicon gate CMOS technology to achieve operating speeds similar to LSTTL gates with the low power consumption of standard CMOS integrated circuits. All devices have the ability to drive 10 LSTTL loads. The HCT logic family is functionally pin compatible with the standard LS logic family.

#### **Ordering Information**

PART NUMBER	TEMP. RANGE ( <sup>o</sup> C)	PACKAGE		
CD54HC132F3A	-55 to 125	14 Ld CERDIP		
CD54HCT132F3A	-55 to 125	14 Ld CERDIP		
CD74HC132E	-55 to 125	14 Ld PDIP		
CD74HC132M	-55 to 125	14 Ld SOIC		
CD74HC132MT	-55 to 125	14 Ld SOIC		
CD74HC132M96	-55 to 125	14 Ld SOIC		
CD74HCT132E	-55 to 125	14 Ld PDIP		
CD74HCT132M	-55 to 125	14 Ld SOIC		
CD74HCT132MT	-55 to 125	14 Ld SOIC		
CD74HCT132M96	-55 to 125	14 Ld SOIC		

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

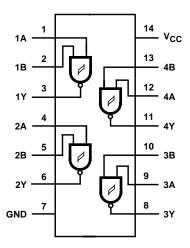
#### Pinout



CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures.

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## Functional Diagram

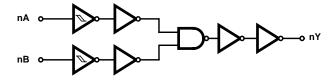


#### TRUTH TABLE

INP	INPUTS						
nA	nB	nY					
L	L	Н					
L	Н	Н					
Н	L	Н					
Н	н	L					

H = High Voltage Level, L = Low Voltage Level

## Logic Symbol



#### **Absolute Maximum Ratings**

DC Supply Voltage, V <sub>CC</sub> 0.5V to 7V
DC Input Diode Current, IIK
For V <sub>I</sub> < -0.5V or V <sub>I</sub> > V <sub>CC</sub> + 0.5V±20mA
DC Output Diode Current, IOK
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_0 > -0.5V$ or $V_0 < V_{CC} + 0.5V$
DC V <sub>CC</sub> or Ground Current, I <sub>CC or</sub> I <sub>GND</sub> ±50mA

#### **Operating Conditions**

Temperature Range ( $T_A$ )
Supply Voltage Range, V <sub>CC</sub>
HC Types2V to 6V
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V <sub>I</sub> , V <sub>O</sub> 0V to V <sub>CC</sub>

#### **Thermal Information**

Thermal Resistance (Typical, Note 1)	θ <sub>JA</sub> ( <sup>o</sup> C/W)
E (PDIP) Package	80
M (SOIC) Package	86
Maximum Junction Temperature	
Maximum Storage Temperature Range	S5 <sup>o</sup> C to 150 <sup>o</sup> C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

#### **DC Electrical Specifications**

			ST ITIONS			25 <sup>0</sup> C		-40 <sup>0</sup> C 1	O 85°C	-55°С Т	O 125 <sup>0</sup> C																		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	ТҮР	МАХ	MIN	МАХ	MIN	MAX																		
HC TYPES			-						-																				
Input Switch Points	V <sub>T</sub> +	-	-	2	0.7	-	1.5	0.7	1.5	0.7	1.5	V																	
(Note 2)				4.5	1.7	-	3.15	1.7	3.15	1.7	3.15	V																	
				6	2.1	-	4.2	2.1	4.2	2.1	4.2	V																	
	V <sub>T</sub> -	-	-	2	0.3	-	1	0.3	1	0.3	1	V																	
				4.5	0.9	-	2.2	0.9	2.2	0.9	2.2	V																	
				6	1.2	-	3	1.2	3	1.2	3	V																	
	V <sub>H</sub>			2	0.2	-	1	0.2	1	0.2	1	V																	
				4.5	0.4	-	1.4	0.4	1.4	0.4	1.4	V																	
				6	0.6	-	1.6	0.6	1.6	0.6	1.6	V																	
High Level Output	V <sub>OH</sub>	V <sub>T</sub> + or	-0.02	2	1.9	-	-	1.9	-	1.9	-	V																	
Voltage CMOS Loads		V <sub>T</sub> -	VT-	v T-	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V															
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V																	
High Level Output										1									[	-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Voltage TTL Loads			-5.2	6	5.48	-	-	5.34	-	5.2	-	V																	
Low Level Output	V <sub>OL</sub>	V <sub>T</sub> + or	0.02	2	-	-	0.1	-	0.1	-	0.1	V																	
Voltage CMOS Loads		V <sub>T</sub> -	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V																	
			0.02	6	-	-	0.1	-	0.1	-	0.1	V																	
Low Level Output	1		4	4.5	-	-	0.26	-	0.33	-	0.4	V																	
Voltage TTL Loads			5.2	6	-	-	0.26	-	0.33	-	0.4	V																	

## CD54HC132, CD74HC132, CD54HCT132, CD74HCT132

			ST ITIONS		25 <sup>0</sup> C			-40 <sup>0</sup> C TO 85 <sup>0</sup> C		-55°C TO 125°C		
PARAMETER	SYMBOL	V <sub>I</sub> (V)	I <sub>O</sub> (mA)	V <sub>CC</sub> (V)	MIN	ТҮР	MAX	MIN	МАХ	MIN	МАХ	
Input Leakage Current	II	V <sub>CC</sub> or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	ICC	V <sub>CC</sub> or GND	0	6	-	-	2	-	20	-	40	μΑ
HCT TYPES												
Input Switch Points	V <sub>T</sub> +	-	-	4.5	1.2	-	1.9	1.2	1.9	1.2	1.9	V
(Note 2)				5.5	1.4	-	2.1	1.4	2.1	1.4	2.1	V
	V <sub>T</sub> -	-	-	4.5	0.5	-	1.2	0.5	1.2	0.5	1.2	V
				5.5	0.6	-	1.4	0.6	1.4	0.6	1.4	V
	V <sub>H</sub>	-	-	4.5	0.4	-	1.4	0.4	1.4	0.4	1.4	V
				5.5	0.4	-	1.5	0.4	1.5	0.4	1.5	V
High Level Output Voltage CMOS Loads		V <sub>T</sub> + <sub>or</sub> V <sub>T</sub> -	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V <sub>OL</sub>	V <sub>T</sub> + <sub>or</sub> V <sub>T</sub> -	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V <sub>CC</sub> and GND	-	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	ICC	V <sub>CC</sub> or GND	0	5.5	-	-	2	-	20	-	40	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I <sub>CC</sub> (Note 3)	V <sub>CC</sub> - 2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μΑ

NOTES:

2. Hysteresis definition, characteristic and test setup see Test Circuits and Waveforms

3. For dual-supply systems theoretical worst case (V<sub>I</sub> = 2.4V, V<sub>CC</sub> = 5.5V) specification is 1.8mA.

## CD54HC132, CD74HC132, CD54HCT132, CD74HCT132

#### **HCT Input Loading Table**

INPUT	UNIT LOADS
nA, nB	0.6

NOTE: Unit Load is  $\Delta I_{CC}$  limit specified in DC Electrical Specifications table, e.g. 360µA max at 25°C.

#### Switching Specifications Input $t_r$ , $t_f = 6ns$

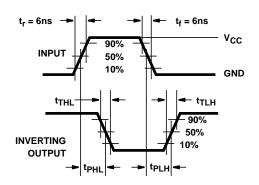
		TEST	v <sub>cc</sub>		25 <sup>0</sup> C		-40°C T	O 85°C	-55°C T	O 125 <sup>0</sup> C	
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES							-				
Propagation Delay	t <sub>PLH</sub> , t <sub>PHL</sub>	$C_L = 50 pF$	2	-	-	125	-	156	-	188	ns
A, B to Y (Figure 1)			4.5	-	-	25	-	31	-	38	ns
			6	-	-	21	-	27	-	32	ns
Propagation Delay A, B to Y	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 15pF	5	-	10	-	-	-	-	-	pF
Transition Times (Figure 1)	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5	-	30	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay A, B to Y (Figure 2)	t <sub>PHL</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	33	-	41	-	50	ns
Propagation Delay A, B to Y	t <sub>PLH</sub> , t <sub>PHL</sub>	C <sub>L</sub> = 15pF	5	-	13	-	-	-	-	-	pF
Transition Times (Figure 2)	t <sub>TLH</sub> , t <sub>THL</sub>	C <sub>L</sub> = 50pF	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	Cl	-	-	-	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 4, 5)	C <sub>PD</sub>	-	5	-	30	-	-	-	-	-	pF

NOTES:

4.  $C_{PD}$  is used to determine the dynamic power consumption, per gate.

5.  $P_D = V_{CC}^2 f_i (C_{PD} + C_L)$  where  $f_i$  = input frequency,  $C_L$  = output load capacitance,  $V_{CC}$  = supply voltage.

#### Test Circuits and Waveforms





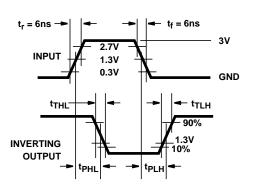


FIGURE 2. HCT TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

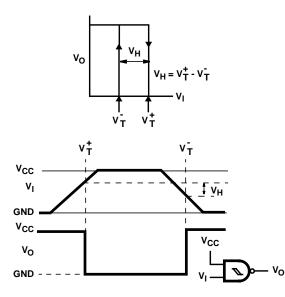


FIGURE 3. HYSTERESIS DEFINITION, CHARACTERISTIC, AND TEST SET-UP

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18-Sep-2008

#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
5962-8984501CA	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HC132F3A	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT132F	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD54HCT132F3A	ACTIVE	CDIP	J	14	1	TBD	A42 SNPB	N / A for Pkg Type
CD74HC132E	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC132EE4	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HC132M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HC132MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132E	ACTIVE	PDIP	N	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT132EE4	ACTIVE	PDIP	Ν	14	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD74HCT132M	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132M96	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132M96E4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132M96G4	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132ME4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132MG4	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132MT	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132MTE4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD74HCT132MTG4	ACTIVE	SOIC	D	14	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available. **OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details. TBD: The Pb-Free/Green conversion plan has not been defined.

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**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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#### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC132M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
CD74HCT132M96	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1



## PACKAGE MATERIALS INFORMATION

11-Mar-2008



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC132M96	SOIC	D	14	2500	346.0	346.0	33.0
CD74HCT132M96	SOIC	D	14	2500	346.0	346.0	33.0

J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE

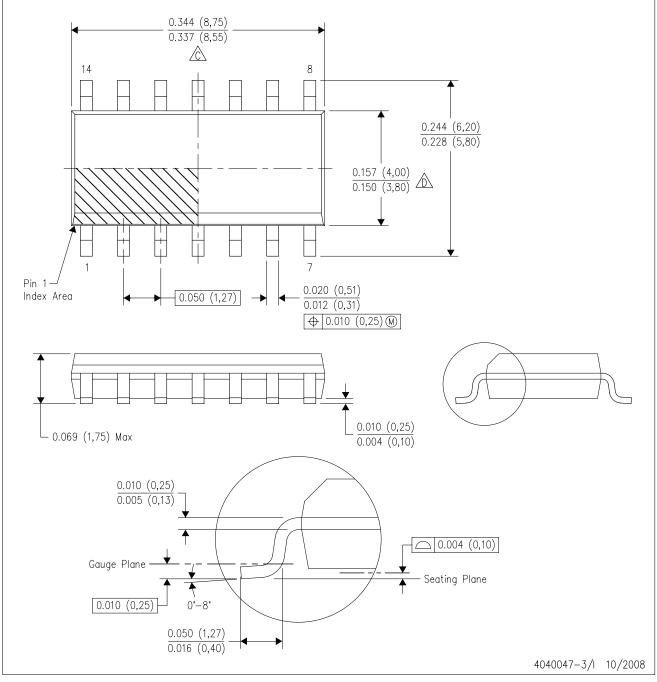


NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

D (R-PDSO-G14)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AB.



## N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



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